

## CORRIGENDUM

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### Electronic structure, lattice dynamics, and thermoelectric properties of bismuth nanowire from first-principles calculation – CORRIGENDUM

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After publication of Lu et al.<sup>1</sup>, the authors requested an additional author be added, thanks to their contributions in calculating the thermoelectric transport of crystal Bi and proposing some valuable suggestions. The additional author's information is as follows:

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The original article has since been updated to reflect the addition.

#### REFERENCE

1. P. Lu, M. Zhang, W.-J. Zou, and C. Kong: Electronic structure, lattice dynamics, and thermoelectric properties of bismuth nanowire from first-principles calculation. *J. Mater. Res.* **32**(12), 2405–2413 (2017). doi: 10.1557/jmr.2017.88.